## Supporting Information

## Effect of four-phonon interaction on phonon thermal conductivity of

## hexagonal VTe2 and puckered pentagonal VTe2

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Fig. S1. Convergence tests of the Q-grid for (a) H-VTe<sub>2</sub> monolayer and (b) PP-VTe<sub>2</sub> monolayer.



Fig. S2. Grüneisen parameter of (a)  $H-VTe_2$  monolayer and (b)  $PP-VTe_2$  monolayer.



Fig. S3. Electron localization functions of (a) H-VTe<sub>2</sub> monolayer and (b-c) PP-VTe<sub>2</sub> monolayer.